NSN 5961-00-902-5876

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-902-5876 **Inclosure Material:** Metal **Overall Length:** 0.500 inches **Overall Diameter:** 0.544 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 3.0 gate trigger voltage, dc **Current Rating Per Characteristic:** 50.00 milliamperes forward current, total rms peak **Maximum Operating Tempurature Per Measurement Point:** 65.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0